

CMOS IC Application Note

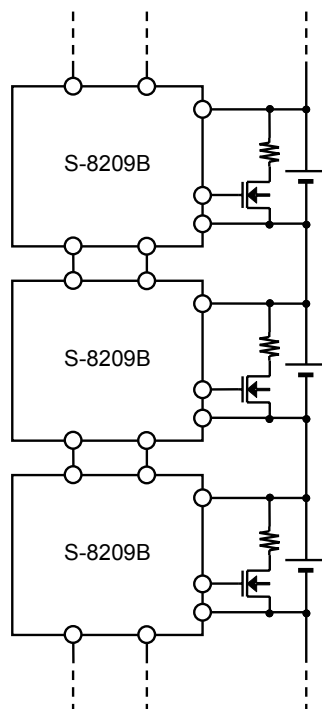
S-8209B Series Usage Guidelines Rev.1.3_00

The S-8209B Series is a battery protection IC with the cell-balance function. This application note is guideline on the typical connection examples when using the S-8209B Series for applications. See the datasheet for details and spec of this IC.

It is possible to configure the following applications with the S-8209B Series.

- A protection circuit with series multi-cell; 2 cells or more
- A battery protection circuit with cell-balance function

- Protection circuit with S-8209B Series for series multi-cells



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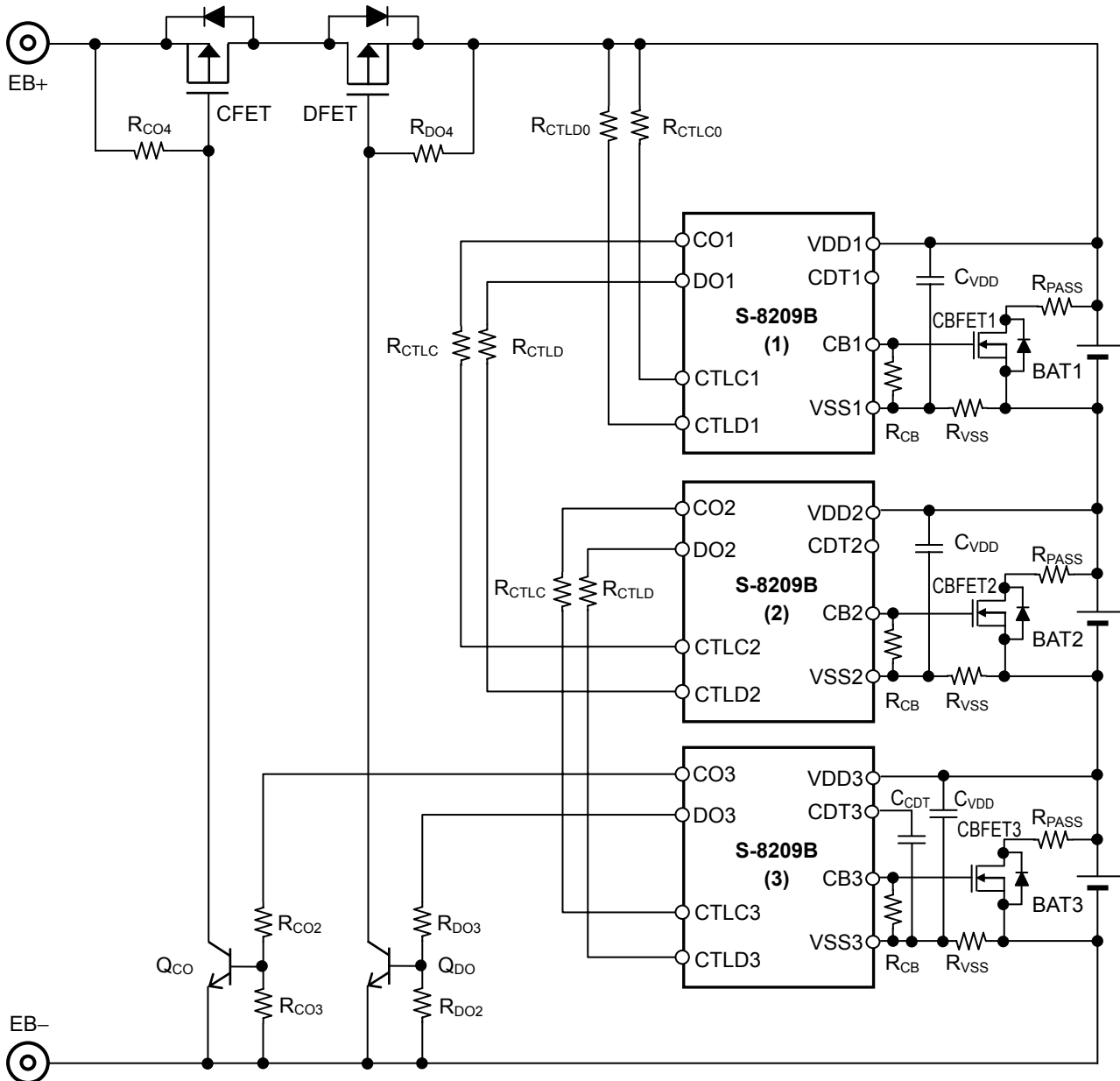
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1. Protection circuit with S-8209B Series for multi-cells

In the connection of S-8209B Series, connecting the CTLC, CTLD pins to the CO, DO pins allows to configure a protection circuit for series-connected batteries.

1.1 Connection example of battery protection IC

Figure 1 shows the example of protection circuit with S-8209B for series multi-cells.



Remark Refer to “2.5 External parts list” for constants of external parts.

Figure 1

- Caution 1.** The above constants may be changed without notice.
- 2.** The example of connection shown above and the constant do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constant.

1.2 Operation

Following is about the operation of protection circuit with S-8209B for series multi-cell shown in **Figure 1**.

1.2.1 Normal status

Following is about the operation of S-8209B Series in the normal status.

The S-8209B goes in the normal status;

In the S-8209B (1), The CTLC1, CTLD1 pins are pulled up to the level of VDD1 pin, BAT1 is more than the overdischarge detection voltage (V_{DL}) and less than the overcharge detection voltage (V_{CU}). The CO1, DO1 pins get the level of VDD1 pin.

In the S-8209B (2), The CTLC2, CTLD2 pins are pulled up to the level of VDD1 pin by the CO1, DO1 pins, BAT2 is more than V_{DL} and less than V_{CU} . The CO2, DO2 pins get the level of VDD2 pin.

In the S-8209B (3), The CTLC3, CTLD3 pins are pulled up to the level of VDD2 pin by the CO2, DO2 pins, BAT3 is more than V_{DL} and less than V_{CU} . The CO3, DO3 pins get the level of VDD3 pin.

The status of each pin in the normal status is shown in **Table 1**.

Table 1

CTLC pin	CTLD pin	Status of battery	CO pin	DO pin
CTLC1 = VDD1	CTLD1 = VDD1	$V_{DL} < BAT1 < V_{CU}$	CO1 = VDD1	DO1 = VDD1
CTLC2 = VDD1	CTLD2 = VDD1	$V_{DL} < BAT2 < V_{CU}$	CO2 = VDD2	DO2 = VDD2
CTLC3 = VDD2	CTLD3 = VDD2	$V_{DL} < BAT3 < V_{CU}$	CO3 = VDD3	DO3 = VDD3

The S-8209B (3) in the normal status turns on the charge control FET (CFET) and the discharge control FET (DFET) via bipolar transistors (Tr1, Tr2) externally set to each CO3 and DO3 pin.

Therefore it is possible to charge/discharge by a charger or a load connected between EB+ and EB-.

1. 2. 2 Status to inhibit charge

Following is about the status to inhibit charge, for example, the S-8209B (1) detects overcharge, the S-8209B (2) and (3) are in the normal status.

The S-8209B (1) goes in the overcharge status when BAT1 gets V_{CU} or more by charging. The CO1 pin is set in high impedance.

The CTLC2 pin of the S-8209B (2) is pulled down to the level of VSS2 pin by the CTLC pin sink current (I_{CTLCL}). The CTLC2 pin gets the level of VSS2 pin by the high impedance CO1 pin. Thus the S-8209B (2) goes in the overcharge status after the level of CTLC2 pin gets the CTLC pin L voltage (V_{CTLCL}) or less. The CO2 pin is set in high impedance.

The CTLC3 pin of the S-8209B (3) is pulled down to the level of VSS3 pin by I_{CTLCL} as well. The CTLC3 pin gets the level of VSS3 pin by the high impedance CO2 pin. The S-8209B (3) also goes in the overcharge status after the level of CTLC3 pin gets V_{CTLCL} or less.

The status of each pin in this case is shown in **Table 2**.

Table 2

CTLC pin	CTLD pin	Status of battery	CO pin	DO pin
CTLC1 = VDD1	CTLD1 = VDD1	$V_{CU} \leq BAT1$	CO1 = High-Z	DO1 = VDD1
CTLC2 = VSS2	CTLD2 = VDD1	$V_{DL} < BAT2 < V_{CU}$	CO2 = High-Z	DO2 = VDD2
CTLC3 = VSS3	CTLD3 = VDD2	$V_{DL} < BAT3 < V_{CU}$	CO3 = High-Z	DO3 = VDD3

The S-8209B (3) in the overcharge status turns off the CFET via a bipolar transistor ($Tr1$) set externally to the CO3 pin. In this case, charging via a charger connected between EB+ and EB- is inhibited.

By this operation the overcharge status is transmitted from the top (S-8209B (1)) to the bottom (S-8209B (3)), from the CO pin to the CTLC pin.

Charging is also inhibited; BAT2 or BAT3 gets V_{CU} or more.

1. 2. 3 Status to inhibit discharge

Following is the status to inhibit discharge, for example, the S-8209B (1) detects overdischarge, the S-8209B (2) and (3) are in the normal status.

The S-8209B (1) goes in the overdischarge status when BAT1 gets V_{DL} or less by discharging. The DO1 pin is set in high impedance.

The CTLD2 pin of the S-8209B (2) is pulled down to the level of VSS2 pin by the CTLD pin sink current (I_{CTLDL}). The CTLD2 pin gets the level of VSS2 pin by the high impedance DO1 pin. Thus the S-8209B (2) goes in the overdischarge status after the level of CTLD2 pin gets the CTLD pin L voltage (V_{CTLDL}) or less. The DO2 pin is set in high impedance.

The CTLD3 pin of the S-8209B (3) is pulled down to the level of VSS3 pin by I_{CTLDL} as well. The CTLD3 pin gets the level of VSS3 pin by the high impedance DO2 pin. The S-8209B (3) also goes in the overdischarge status after the level of CTLD3 pin gets V_{CTLDL} or less.

The status of each pin in this case is shown in **Table 3**.

Table 3

CTLC pin	CTLD pin	Status of battery	CO pin	DO pin
CTLC1 = VDD1	CTLD1 = VDD1	$BAT1 \leq V_{DL}$	CO1 = VDD1	DO1 = High-Z
CTLC2 = VDD1	CTLD2 = VSS2	$V_{DL} < BAT2 < V_{CU}$	CO2 = VDD2	DO2 = High-Z
CTLC3 = VDD2	CTLD3 = VSS3	$V_{DL} < BAT3 < V_{CU}$	CO3 = VDD3	DO3 = High-Z

The S-8209B (3) in the overdischarge status turns off the DFET via a bipolar transistor (Tr2) externally set to the DO3 pin. In this case, discharging to a load connected between EB+ and EB- is inhibited.

By this operation the overdischarge status is transmitted from the top (S-8209B (1)) to the bottom (S-8209B (3)), from the DO pin to the CTLD pin.

Charging is also inhibited; BAT2 or BAT3 gets V_{DL} or less.

1. 2. 4 Cell-balance function

The S-8209B Series has two types of cell-balance function.

(1) Charge cell-balance function

In **Figure 1**, The S-8209B (1) sets the CB1 pin at the level of VDD1 pin when BAT1 gets the cell-balance detection voltage (V_{BU}) or more by charging. By this operation, the cell-balance control FET (CBFET1) is turned on so that the cell-balance control FET bypasses the charge current which flows into BAT1.

At this point, if BAT2, BAT3 are less than V_{BU} , the speed to charge BAT1 gets slower than to charge BAT2, BAT3. This is the charge cell-balance function. Even if any of battery voltages reaches V_{BU} , the cell-balance control FET which corresponds to each battery turns on and the cell-balance is adjusted.

The S-8209B Series turns off the cell-balance control FET when the battery voltage decreases to the cell-balance release voltage (V_{BL}) or less again by discharging.

(2) Discharge cell-balance function

As seen in “1. 2. 3 Status to inhibit discharge”, the S-8209B (1) goes in the overdischarge status when BAT1 gets V_{DL} or less by discharging. After that, the S-8209B (2) also goes in the overdischarge status via the DO1 pin and the CTLD2 pin.

At this point, if BAT2 is more than V_{DL} , the S-8209B (2) turns on the cell-balance control FET (CBFET2). This is the discharge cell-balance function. The S-8209B (3) also goes in the overdischarge status via the DO2 pin and the CTLD3 pin. As well in case that BAT3 is more than V_{DL} , the S-8209B (3) turns on the cell-balance control FET (CBFET3).

By this operation after BAT1 has reached V_{DL} , BAT2 and BAT3 which have the higher voltage than BAT1 start discharge; via the cell-balance control FETs (CBFET2, CBFET3) which correspond to each battery. Thus the cell-balance is adjusted after a certain period.

The S-8209B Series turns off the cell-balance control FET which corresponds to each battery when the voltages of BAT2, BAT3 decrease to V_{DL} or less.

Caution The cell-balance control FET may turn on immediately after connected the battery; a battery having the voltage V_{BL} or more, or a battery having the voltage overdischarge release voltage (V_{DU}) or less is included among batteries, in composing a protection circuit shown in **Figure 1**.

1. 2. 5 Delay circuit

Connecting a delay capacitor only to the CDT3 pin of the S-8209B (3), as seen in **Figure 1**, allows to gain the detection delay time (t_{DET}) and the release delay time (t_{REL}). In detecting by any of batteries, each delay time is the same length.

(1) Detection delay time (t_{DET})

BAT1 gets V_{CU} or more by charging, the CTLC2 pin gets the level of VSS2 pin because a capacitor is not connected to the CDT1 pin so that the CO1 pin is set in high impedance after delay of several hundred μ s.

After that in the S-8209B (2), the level of CTLC2 pin gets V_{CTLCL} or less, after delay of several hundred μ s the CO2 pin is set in high impedance.

In the S-8209B (3), after delay of $10.0 [M\Omega] (Typ.) \times 0.01 [\mu F] = 0.1 [s] (Typ.)$, the CO3 pin is set in high impedance because C_{CDT} is connected to the CDT3 pin.

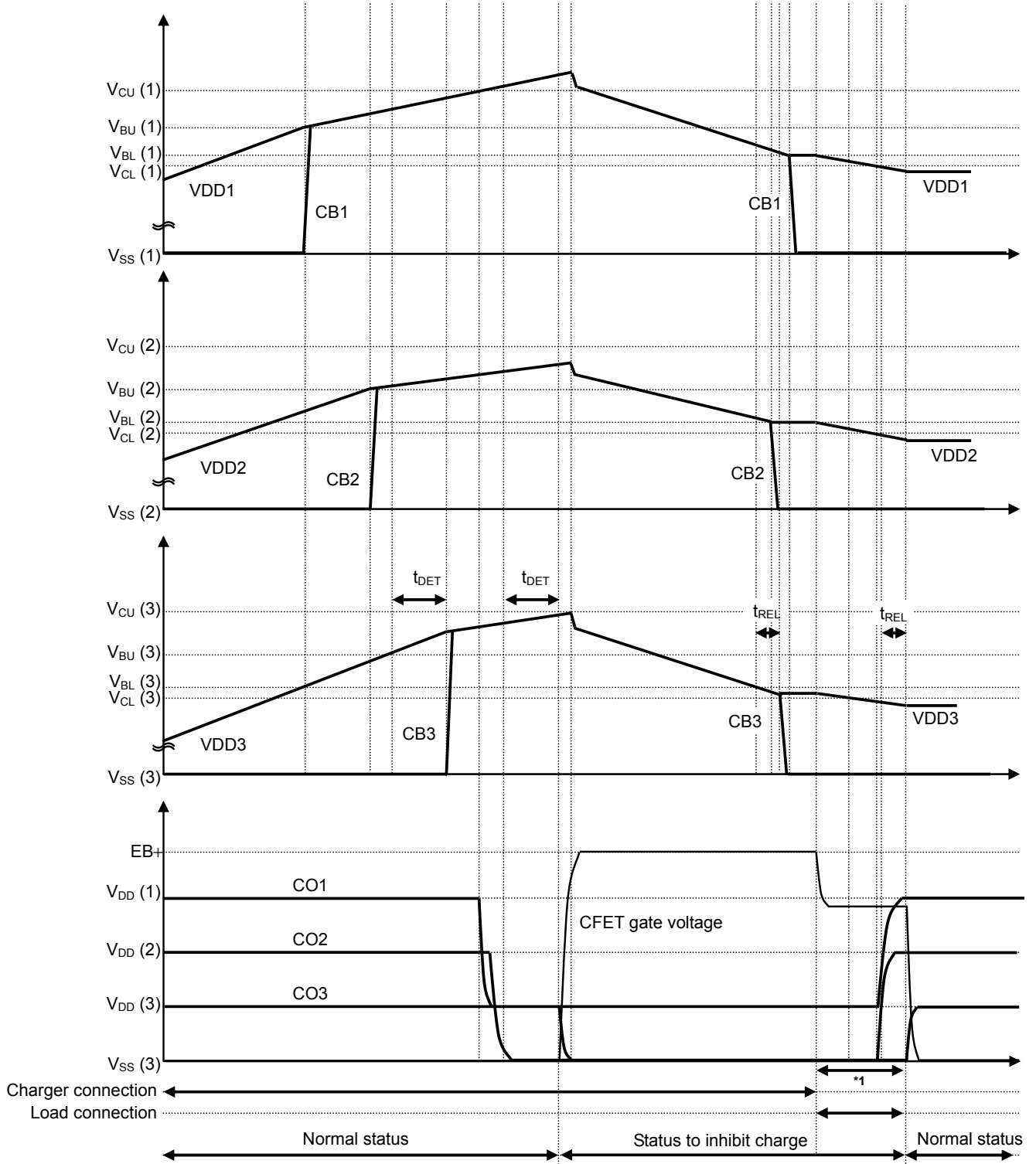
Even if any of batteries detects, by this operation, users are able to gain the detection delay time almost the same to delay time of the S-8209B (3), because it defines the whole delay time in the S-8209B Series.

(2) Release delay time (t_{REL})

The S-8209B Series also has the release delay time (t_{REL}), and this delay time is set its length as approx. 1/10 of the detection delay time. Connecting a delay capacitor only to the CDT3 pin of the S-8209B (3) allows having the same release delay time, as well as in the detection delay time.

1.3 Timing chart

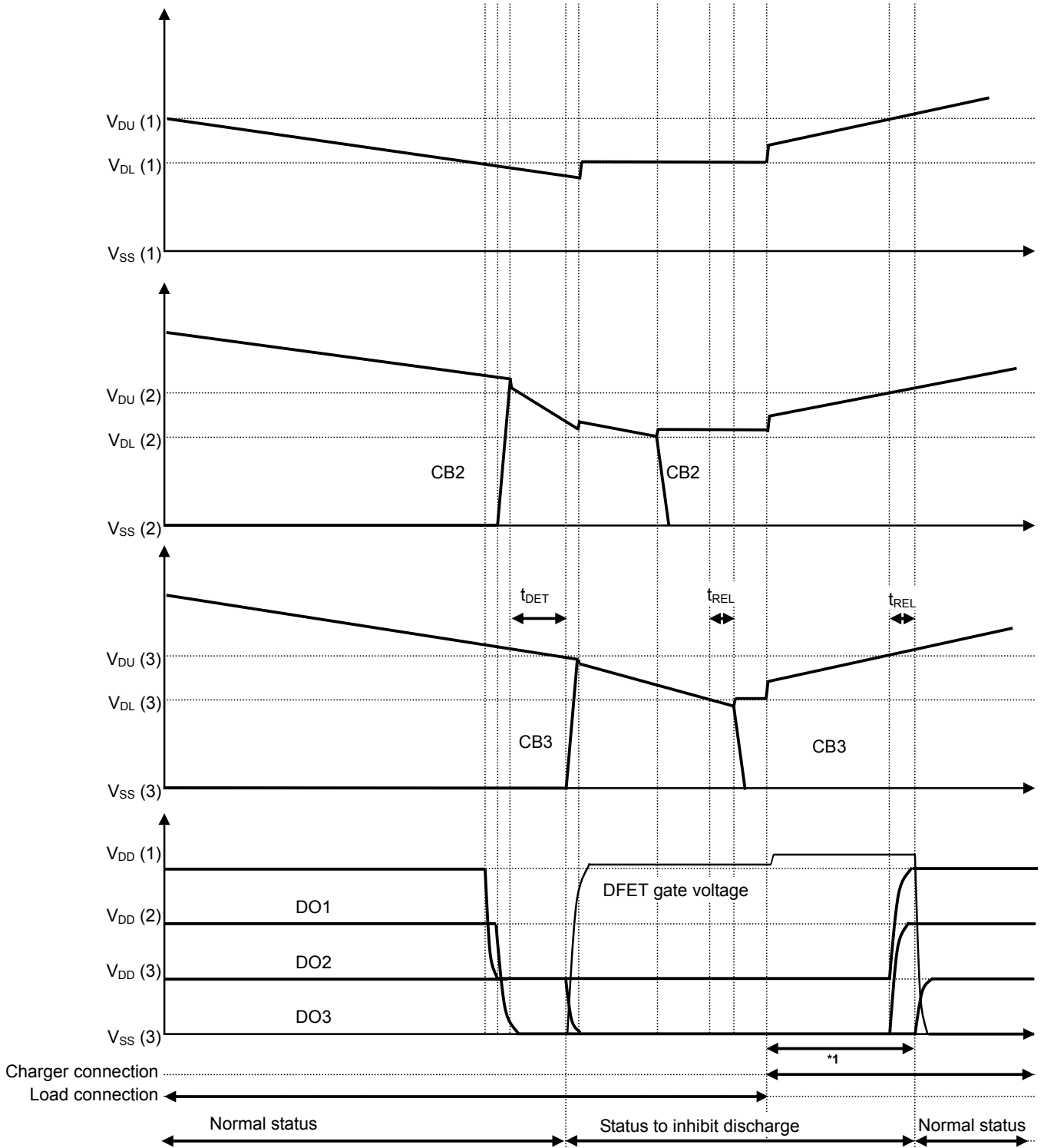
1.3.1 Overcharge detection



*1. In this period, the discharge current flows via a parasitic diode in the CFET.

Figure 2

1.3.2 Overdischarge detection



*1. In this period, the charge current flows via a parasitic diode in the DFET.

Figure 3

1.4 Demonstration data of charge cell-balance detection

The demonstration data shows cell-balance for 3-series lithium ion secondary battery using the S-8209BAA.

1.4.1 High ratio of bypass current to charge current

Charger: a constant current charger (0.05 C = 145 mA)

S-8209BAA charge cell-balance, 0.05 C constant current charger

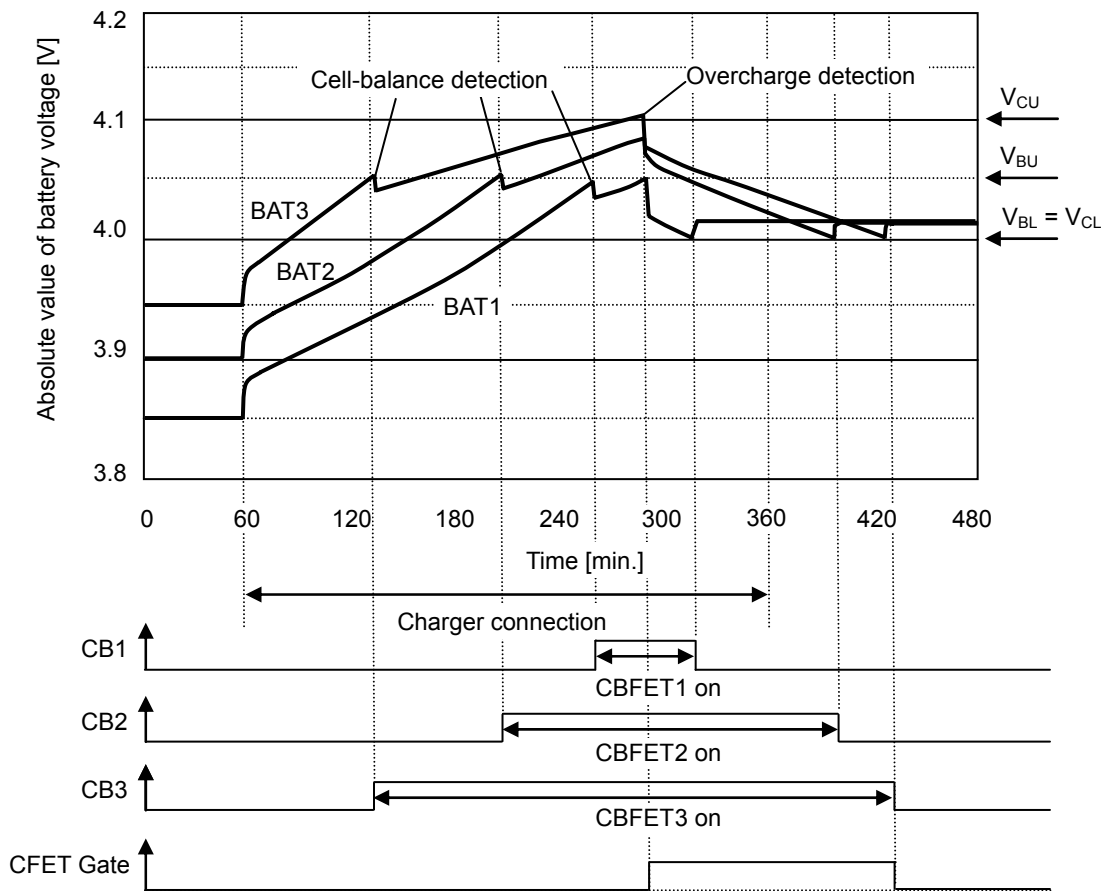


Figure 4

Test conditions

Test circuit: Figure 1

IC: S-8209BAA ($V_{CU} = 4.100\text{ V}$, $V_{CL} = 4.000\text{ V}$, $V_{BU} = 4.050\text{ V}$, $V_{BL} = 4.000\text{ V}$, $V_{DL} = 2.500\text{ V}$, $V_{DU} = 2.700\text{ V}$)

Battery: 3-series cell lithium ion secondary battery, Nominal capacitance: 2.9 Ah, Size: 18650

$R_{PASS} = 51\ \Omega$ (1 W) \rightarrow Bypass current = $4.1\text{ V} / 51\ \Omega = 80\text{ mA}$

1. 4. 2 Low ratio of bypass current to charge current

When the ratio of bypass current to charge current is low, repeating cell-balance cycle enables to adjust cell-balance.

Charger: a constant current charger (0.1 C = 290 mA)

S-8209BAA charge cell-balance, 0.1 C constant current charger

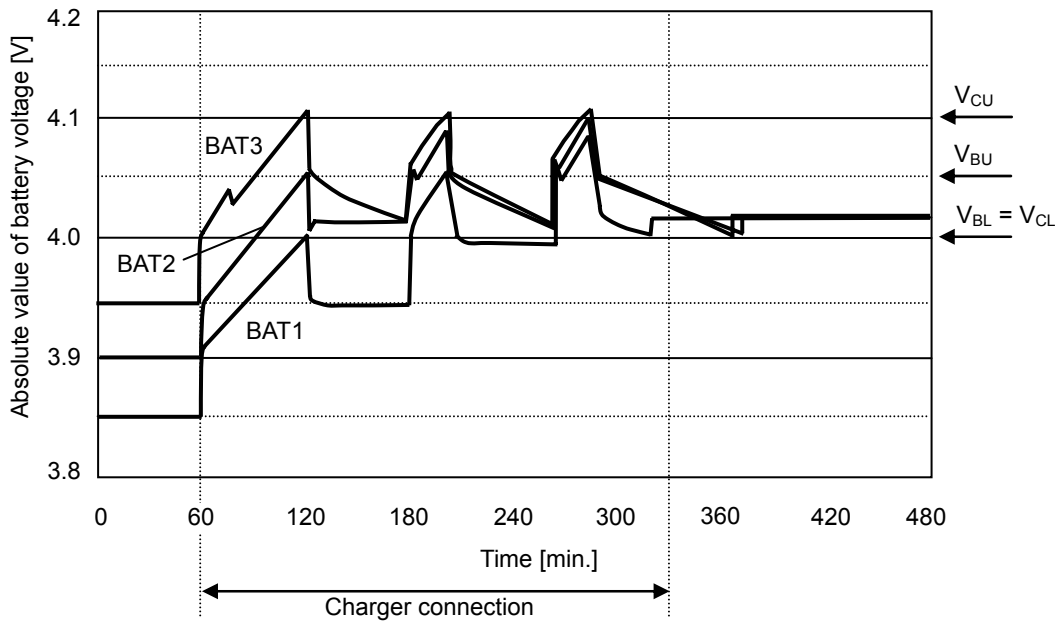


Figure 5

Test conditions

Test circuit: **Figure 1**

IC: S-8209BAA ($V_{CU} = 4.100\text{ V}$, $V_{CL} = 4.000\text{ V}$, $V_{BU} = 4.050\text{ V}$, $V_{BL} = 4.000\text{ V}$, $V_{DL} = 2.500\text{ V}$, $V_{DU} = 2.700\text{ V}$)

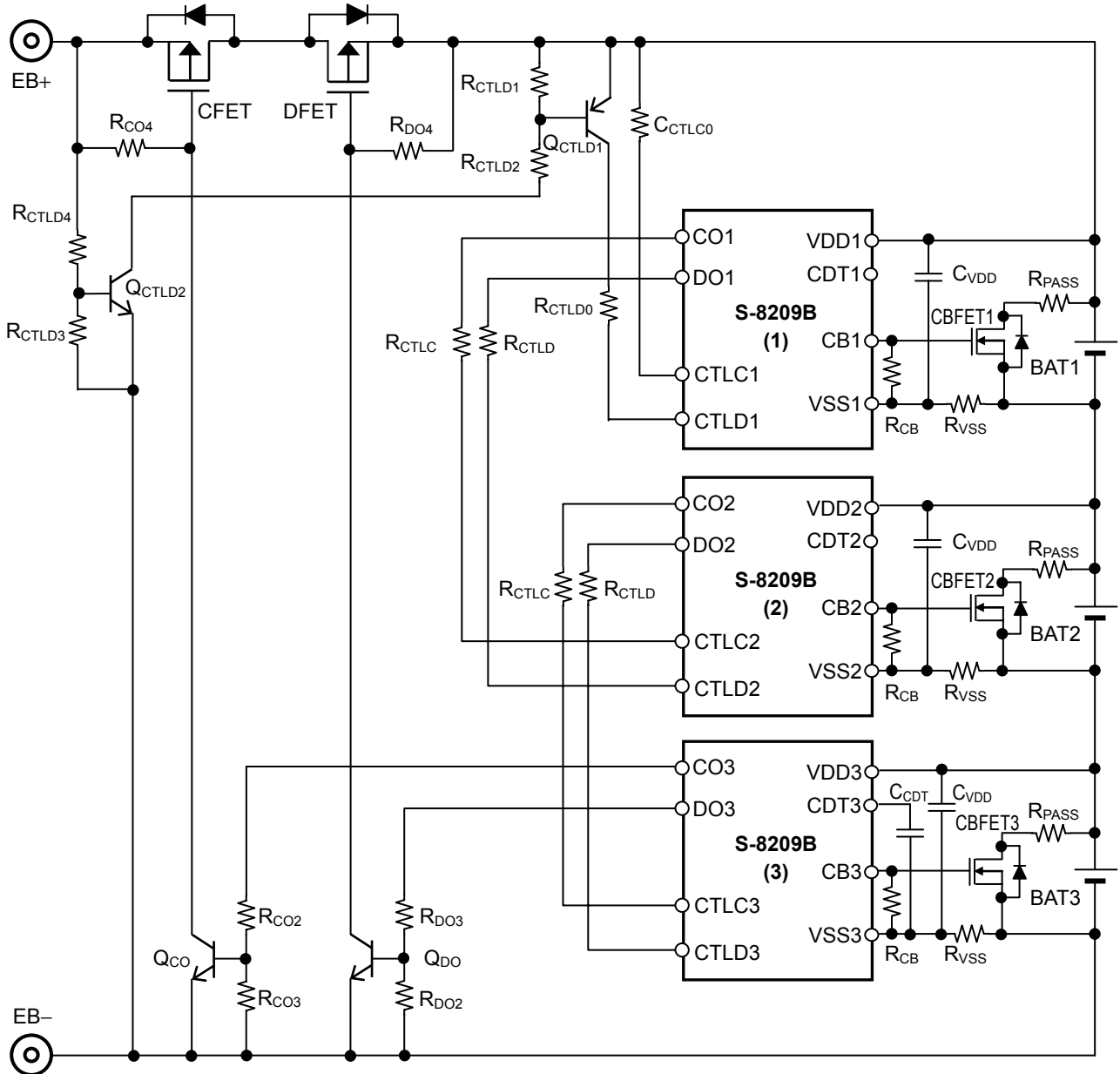
Battery: 3-series cell lithium ion secondary battery, Nominal capacitance: 2.9 Ah, Size: 18650

$R_{PASS} = 51\ \Omega$ (1 W) \rightarrow bypass current = $4.1\text{ V} / 51\ \Omega = 80\text{ mA}$

2. Application circuit, added the function to transmit overdischarge status

2.1 Connection example of battery protection IC

Setting bipolar transistors (Q_{CTLD1} , Q_{CTLD2}) allows adding the function to transmit the overdischarge status from the bottom (S-8209B (3)) to the top (S-8209B (1)).



Remark Refer to “2.5 External parts list” for constants of external parts.

Figure 6

- Caution 1. The above constants may be changed without notice.
- 2. The example of connection shown above and the constant do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constant.

2.2 Operation

The operation of example of protection circuit, in **Figure 6**, with S-8209B for series multi-cells is as follows.

Setting bipolar transistors (Tr3, Tr4) to the circuit in **Figure 1** allows adding the function to transmit the overdischarge status from the bottom (S-8209B (3)) to the top (S-8209B (1)). By this, even if any IC among the S-8209B (1) to (3) first goes in the overdischarge status, it is possible to turn on all other cell-balance control FETs (CBFET) of the S-8209B Series. Thus cell-balance is certainly adjusted.

Following is about the operation in the status to inhibit discharge, when the S-8209B (2) detects overdischarge, and the S-8209B (1), (3) are in the normal status.

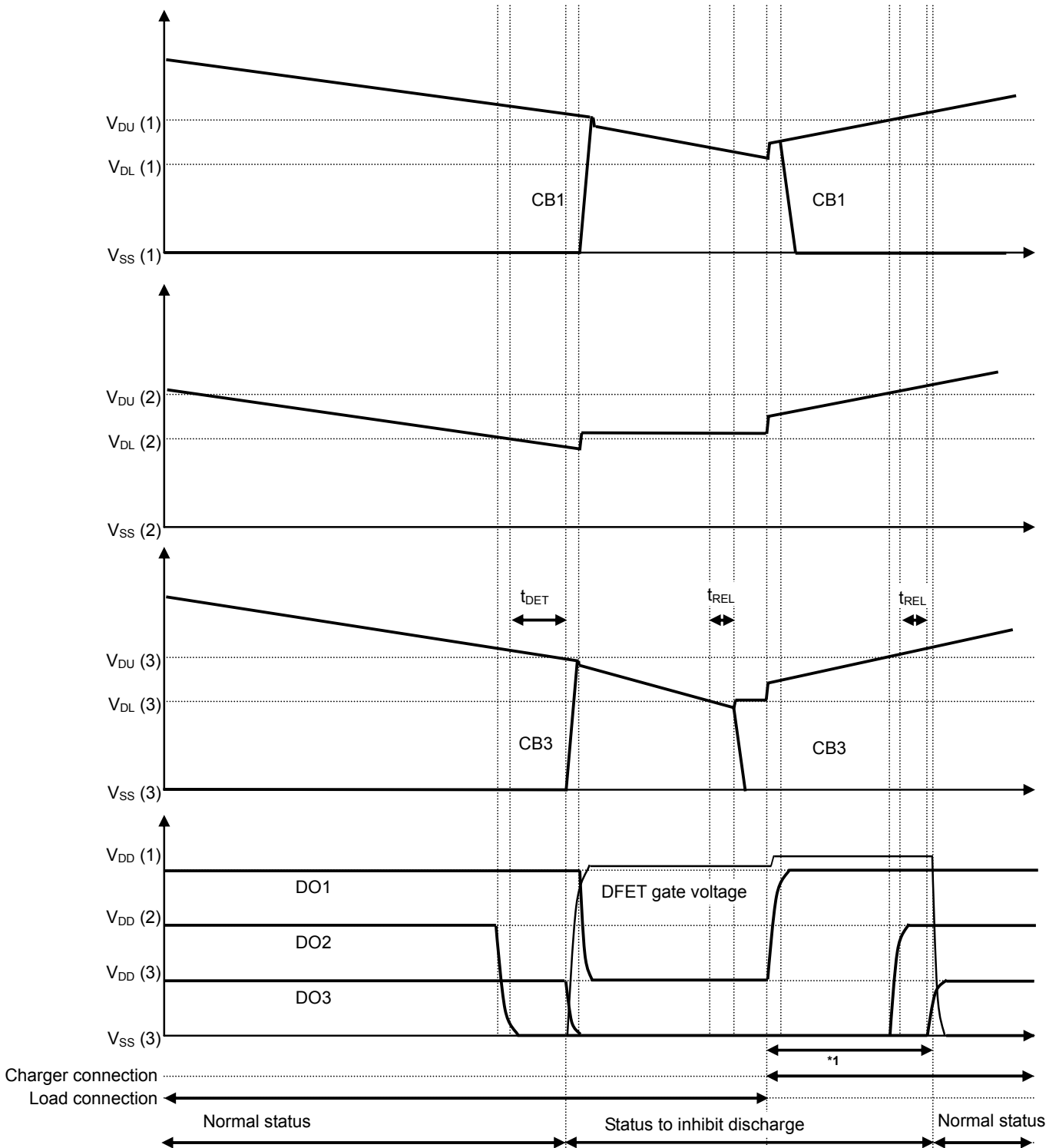
1. The S-8209B (2) goes in the overdischarge status when BAT2 decreases to V_{DL} or less by discharging. The DO2 pin is set in high impedance.
2. The S-8209B (3) also goes in the overdischarge status via the DO2 pin to the CTLD3 pin.
3. The S-8209B (3) turns on the cell-balance control FET (CBFET3) by the discharge cell-balance function.
4. The S-8209B (3) in the overdischarge status turns off DFET via a bipolar transistor (Tr2) and inhibits discharging to a load connected between EB+ and EB-.
5. The EB+pin is pulled down by a load connected between EB+ and EB-.
6. Tr3, Tr4 are turned off and the CTLD1 pin of the S-8209B (1) is set in high impedance.
7. The S-8209B (1) also goes in the overdischarge status. The cell-balance control FET (CBFET1) turns on by the discharge cell-balance function.

As mentioned above, even in case that the S-8209B (2) first detects overdischarge by voltage drop in BAT2, the overdischarge status is transmitted from the S-8209B (3) to S-8209B (1) via Tr3, Tr4. As a result all (1) to (3) of the S-8209B go in the overdischarge status so that cell-balance is adjusted by the discharge cell-balance function, when each BAT is more than V_{DL} . The cell-balance FET which corresponds to each battery turns off by the voltages of BAT1 to 3 that decreased to V_{DL} or less.

And Tr3, Tr4 are turned on by connecting a charger between EB+ and EB- after inhibit discharging, and the CTLD1 pin is pulled up to the level of VDD1. In this case, the cell-balance control FET (CBFET1) turns off although the voltage of BAT1 does not reach V_{DL} or less.

Caution The cell-balance control FET may turn on immediately after connected the battery; although not included a battery having the voltage V_{BL} or more, or a battery having the voltage overdischarge release voltage (V_{DU}) or less among batteries, in composing a protection circuit shown in **Figure 6**. To turn off the cell-balance control FET, connect a charger between EB+ and EB-.

2.3 Timing chart of overdischarge detection



*1. In this period, the charge current flows via a parasitic diode in the DFET.

Figure 7

2.4 Demonstration data of overdischarge cell-balance detection

The demonstration data shows cell-balance for 3-series lithium ion secondary battery using the S-8209BAA.

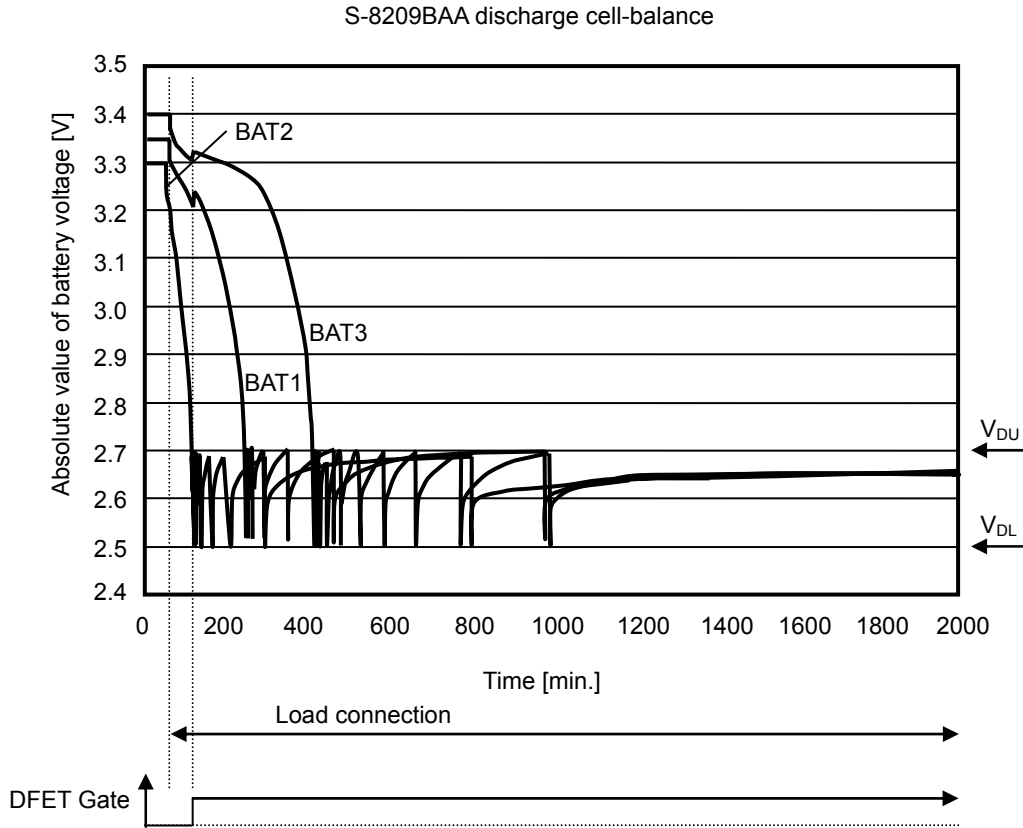


Figure 8

Test conditions

Test circuit: **Figure 6**

IC: S-8209BAA ($V_{CU} = 4.100\text{ V}$, $V_{CL} = 4.000\text{ V}$, $V_{BU} = 4.050\text{ V}$, $V_{BL} = 4.000\text{ V}$, $V_{DL} = 2.500\text{ V}$, $V_{DU} = 2.700\text{ V}$)

Battery: 3-series cell lithium ion secondary battery, Nominal capacitance: 2.9 Ah, Size: 18650

$R_{PASS} = 51\ \Omega$ (1 W) \rightarrow bypass current = $2.5\text{ V} / 51\ \Omega = 49\text{ mA}$

Load: $100\ \Omega$

Battery voltage's oscillation

1. The cell-balance control FET turns off when the battery voltage decrease to the overdischarge detection voltage (V_{DL}) or less.
2. Discharge via the cell-balance control FET stops so that the battery voltage rises.
3. The cell-balance control FET turns on when the battery voltage increases to the overdischarge release voltage (V_{DU}) or more.
4. Discharge via the cell-balance control FET starts so that the battery voltage falls.

Repeating the procedures 1 to 4 enables to adjust cell-balance.

2.5 External parts list

Table 4 shows external parts in the connection examples in Figure 1, 6 and 9.

Table 4

Symbol	Typical	Unit	Parts name	Maker
CBFET1 to CBFET5	—	—	SSM3K301T	TOSHIBA CORPORATION
R _{PASS} ^{*1}	—	—	—	—
R _{VSS}	470	Ω	MCR03	ROHM CO., LTD.
R _{CB}	10	MΩ	MCR03	ROHM CO., LTD.
C _{VDD}	0.1	μF	GRM188	Murata Manufacturing Co., Ltd.
C _{CDT}	0.01	μF	GRM188	Murata Manufacturing Co., Ltd.
Q _{CTLD1}	—	—	25A1037AK	ROHM CO., LTD.
Q _{CTLD2}	—	—	2SC2412K	ROHM CO., LTD.
Q _{CO}	—	—	2SC2412K	ROHM CO., LTD.
Q _{DO}	—	—	2SC2412K	ROHM CO., LTD.
R _{CTL_C} ^{*2}	—	—	—	—
R _{CTL_D} ^{*2}	—	—	—	—
R _{CTL_{C0}}	1	kΩ	MCR03	ROHM CO., LTD.
R _{CTL_{D0}}	1	kΩ	MCR03	ROHM CO., LTD.
R _{CTL_{D1}}	1	MΩ	MCR03	ROHM CO., LTD.
R _{CTL_{D2}}	4.7	MΩ	MCR03	ROHM CO., LTD.
R _{CTL_{D3}}	1	MΩ	MCR03	ROHM CO., LTD.
R _{CTL_{D4}}	4.7	MΩ	MCR03	ROHM CO., LTD.
R _{CO1}	1	MΩ	MCR03	ROHM CO., LTD.
R _{CO2}	510	kΩ	MCR03	ROHM CO., LTD.
R _{CO3}	1	MΩ	MCR03	ROHM CO., LTD.
R _{CO4}	1	MΩ	MCR03	ROHM CO., LTD.
R _{DO1}	1	MΩ	MCR03	ROHM CO., LTD.
R _{DO2}	510	kΩ	MCR03	ROHM CO., LTD.
R _{DO3}	1	MΩ	MCR03	ROHM CO., LTD.
R _{DO4}	1	MΩ	MCR03	ROHM CO., LTD.
CFET	—	—	—	—
DFET	—	—	—	—

*1. Pay attention to the rated electric powers.

*2. Select R_{CTL_C} and R_{CTL_D} from 0 Ω to 1 kΩ.

Caution 1. The above constants may be changed without notice.

2. The example of connection shown above and the constant do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constant.
3. Select external parts considering its pressure when configuring a series protection cell with 5 cells or more.

S-8209B Series Usage Guidelines

4. Precaution

- The usage described in this application note is typical example with our IC. Perform evaluation fully before use.
- When designing for mass production using an application circuit described herein, the product deviation and temperature characteristics of the external parts should be taken into consideration. SII shall not bear any responsibility for patent infringements related to products using the circuits described herein.
- SII claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

5. Related source

Refer to the following datasheet for details of the S-8209B Series.

S-8209B Series Datasheet

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